

DSF8025SE / DSF8025SG

Fast Recovery Diode

DS6153-1 July 2014 (LN31793)

 V_{RRM}

I_{F(AV)}

FSM

Q,

t,,

KEY PARAMETERS

2500V

650A

7500A

540µC

5.0µs

APPLICATIONS

- Induction Heating
- A.C. Motor Drives
- Inverters And Choppers
- Welding
- High Frequency Rectification
- UPS

FEATURES

- Double side cooling
- High surge capability
- Low recovery charge

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V _{RRM} V	Conditions
DSF8025SE25	2500	$V_{RSM} = V_{RRM} + 100V$
DSF8025SG25		
DSF8025SE24	2400	
DSF8025SG24		
DSF8025SE23	2300	
DSF8025SG23		
DSF8025SE22	2200	
DSF8025SG22		
DSF8025SE21	2100	
DSF8025SG21 DSF8025SE20 DSF8025SG20	2000	

Lower voltage grades available.

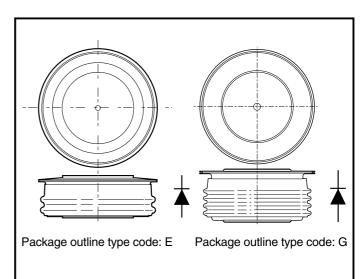
ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

DSF8025SE23 for 2300V product in an 'E' outline,

DSF8025SG23 for 2300V product in an 'G' outline,

Note: Please use the complete part number when ordering and quote this number in any future correspondance relating to your order.



(See package details for further information)

Fig. 1 Package outlines



CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units		
Double Sic	Double Side Cooled					
I _{F(AV)}	Mean forward current	Half wave resistive load, $T_{case} = 65^{\circ}C$	650	А		
I _{F(RMS)}	RMS value	$T_{case} = 65^{\circ}C$	1020	А		
I _F	Continuous (direct) forward current	$T_{case} = 65^{\circ}C$	785	Α		
Single Side Cooled (Anode side)						
I _{F(AV)}	Mean forward current	Half wave resistive load, $T_{case} = 65^{\circ}C$	385	А		
I _{F(RMS)}	RMS value	$T_{case} = 65^{\circ}C$	604	Α		
I _F	Continuous (direct) forward current	$T_{case} = 65^{\circ}C$	465	А		

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 0% V_{RRM} , $T_i = 150^{\circ}C$	7.5	kA
l²t	I ² t for fusing	Toms than sine, with 0 % V_{RRM} , $T_j = 150 \text{ C}$	281 x 10 ³	A²s
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 50% V _{BBM} T _i = 150°C	6.0	kA
l ² t	I ² t for fusing	$\mathbf{V}_{\text{RRM}}, \mathbf{V}_{j} = 150 \text{ C}$	180 x 10 ³	A²s

THERMAL AND MECHANICAL DATA

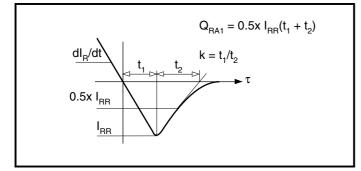
Symbol	Parameter	Conditions		Min.	Max.	Units
R _{th(i-c)}	Thermal resistance - junction to case	Double side cooled	dc	-	0.047	°C/W
		Single side cooled	Anode dc	-	0.094	°C/W
			Cathode dc	-	0.094	°C/W
R _{th(c-h)} Thermal resistance - case to	The second	Clamping force 8.0kN with mounting compound	Double side	-	0.018	°C/W
	mermanesistance - case to neatsink		Single side	-	0.036	°C/W
T _{vj}	Virtual junction temperature	Forward (conducting)		-	150	°C
T _{stg}	Storage temperature range			-55	175	°C
-	Clamping force		7.0	9.0	kN	



CHARACTERISTICS

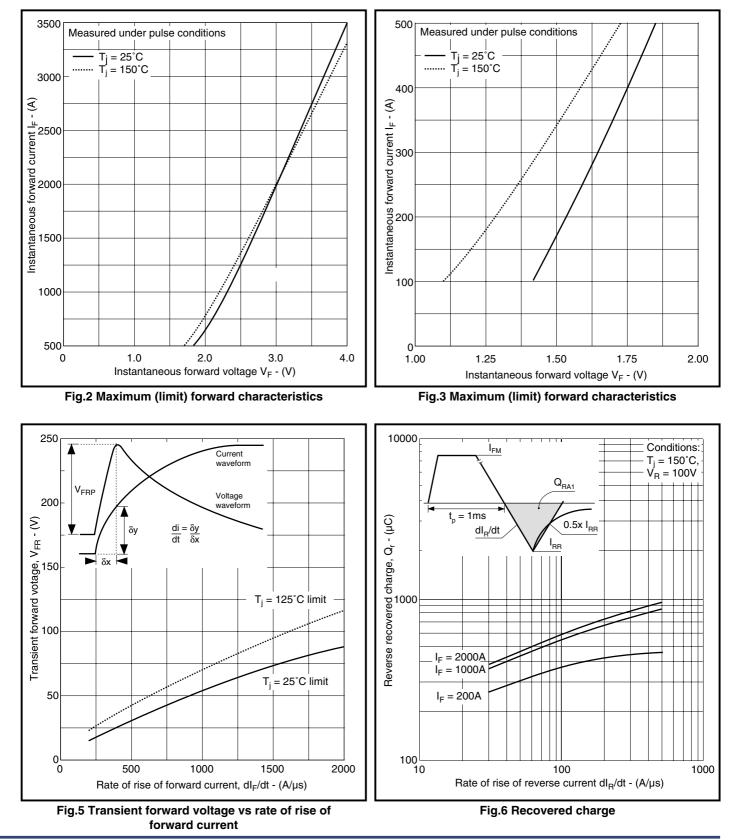
Symbol	Parameter	Conditions	Тур.	Max.	Units
V _{FM}	Forward voltage	At 1000A peak, T _{case} = 25°C	-	2.3	v
I _{RM}	Peak reverse current	At V_{RRM} , $T_{\text{case}} = 150^{\circ}\text{C}$	-	50	mA
t _{rr}	Reverse recovery time		-	5.0	μs
Q _{RA1}	Recovered charge (50% chord)	I _F = 1000A, di _{RR} /dt = 100A/μs	-	540	μC
I _{RR}	Reverse recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	235	Α
к	Soft factor		1.8	-	-
V _{TO}	Threshold voltage	At $T_{vj} = 150^{\circ}C$	-	1.48	v
r _T	Slope resistance	At $T_{vj} = 150^{\circ}C$	-	0.8	mΩ
V _{FRP}	Peak forward recovery voltage	di/dt = 1000A/µs, T _j = 125°C	70	-	v

DEFINITION OF K FACTOR AND $\mathbf{Q}_{_{\mathbf{RA1}}}$

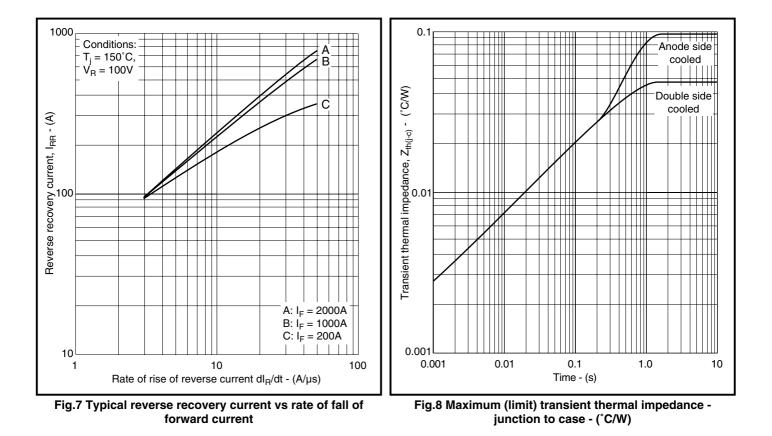




CURVES









PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

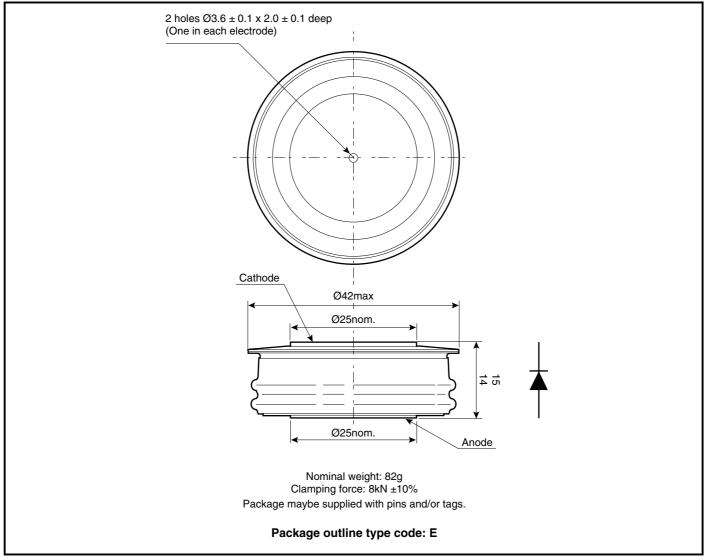


Fig. 9 Package details - E



PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

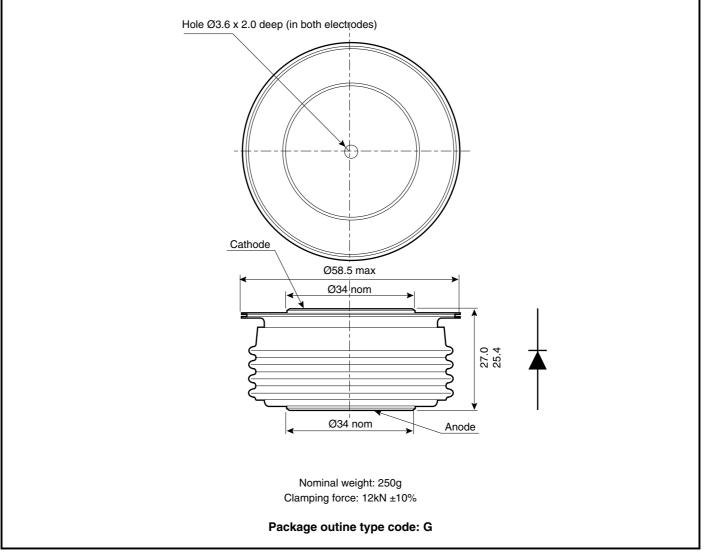


Fig. 10 Package details - G



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